

MOS INTEGRATED CIRCUIT μ PD44321181, 44321321, 44321361

32M-BIT ZEROSB[™] SRAM FLOW THROUGH OPERATION

* Description

The μ PD44321181 is a 2,097,152-word by 18-bit, the μ PD44321321 is a 1,048,576-word by 32-bit and the μ PD44321361 is a 1,048,576-word by 36-bit ZEROSB static RAM fabricated with advanced CMOS technology using full CMOS six-transistor memory cell.

The μ PD44321381, μ PD44321321 and μ PD44321361 are optimized to eliminate dead cycles for read to write, or write to read transitions. These ZEROSB static RAMs integrate unique synchronous peripheral circuitry, 2-bit burst counter and output buffer as well as SRAM core. All input registers are controlled by a positive edge of the single clock input (CLK).

The μ PD44321181, μ PD44321321 and μ PD44321361 are suitable for applications which require synchronous operation, high speed, low voltage, high density and wide bit configuration, such as buffer memory.

ZZ has to be set LOW at the normal operation. When ZZ is set HIGH, the SRAM enters Power Down State ("Sleep"). In the "Sleep" state, the SRAM internal state is preserved. When ZZ is set LOW again, the SRAM resumes normal operation.

The μ PD44321181, μ PD44321321 and μ PD44321361 are packaged in 100-pin PLASTIC LQFP with a 1.4 mm package thickness or 165-pin PLASTIC FBGA for high density and low capacitive loading.

Features

- ★ Low voltage core supply: $V_{DD} = 3.3 \pm 0.165V$ (-A65, -A75, -A85, -A65Y, -A75Y, -A85Y) $V_{DD} = 2.5 \pm 0.125V$ (-C75, -C85, -C75Y, -C85Y)
 - Synchronous operation
- ◆ Operating temperature : T_A = 0 to 70 °C (-A65, -A75, -A85, -C75, -C85)

 $T_A = -40 \text{ to } +85 \,^{\circ}\text{C} \text{ (-A65Y, -A75Y, -A85Y, -C75Y, -C85Y)}$

- 100 percent bus utilization
- · Internally self-timed write control
- Burst read / write : Interleaved burst and linear burst sequence
- Fully registered inputs and outputs for flow through operation
- · All registers triggered off positive clock edge
- 3.3V or 2.5V LVTTL Compatible : All inputs and outputs
- Fast clock access time : 6.5 ns (133 MHz), 7.5 ns (117 MHz), 8.5 ns (100 MHz)
- Asynchronous output enable : /G
- Burst sequence selectable : MODE
- Sleep mode : ZZ (ZZ = Open or Low : Normal operation)
- Separate byte write enable : /BW1 to /BW4 (μ PD44321321 and μ PD44321361)

/BW1 and /BW2 (μPD44321181)

- Three chip enables for easy depth expansion
- Common I/O using three state outputs

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★ Ordering Information

(1/2)

Part number	Access Time ns	Clock Frequency MHz	Core Supply Voltage V	I/O Interface	Operating Temperature °C	Package
μPD44321181GF-A65	6.5	133	3.3 ± 0.165	3.3 V or	0 to 70	100-pin PLASTIC LQFP
μPD44321181GF-A75	7.5	117		2.5 V LVTTL		(14 x 20)
μPD44321181GF-A85	8.5	100				
μPD44321321GF-A65	6.5	133				
μPD44321321GF-A75	7.5	117				
μPD44321321GF-A85	8.5	100				
μPD44321361GF-A65	6.5	133				
μPD44321361GF-A75	7.5	117				
μPD44321361GF-A85	8.5	100				
μPD44321181GF-C75	7.5	117	2.5 ± 0.125	2.5 V LVTTL		
μPD44321181GF-C85	8.5	100				
μPD44321321GF-C75	7.5	117				
μPD44321321GF-C85	8.5	100				
μPD44321361GF-C75	7.5	117				
μPD44321361GF-C85	8.5	100				
μPD44321181F1-A65-FQ2 Note	6.5	133	3.3 ± 0.165	3.3 V or		165-pin PLASTIC FBGA
μPD44321181F1-A75-FQ2 Note	7.5	117		2.5 V LVTTL		(15 x 17)
μPD44321181F1-A85-FQ2 ^{Note}	8.5	100				
μPD44321321F1-A65-FQ2 ^{Note}	6.5	133				
μPD44321321F1-A75-FQ2 Note	7.5	117				
μPD44321321F1-A85-FQ2 ^{Note}	8.5	100				
μ PD44321361F1-A65-FQ2 $^{ m Note}$	6.5	133				
μ PD44321361F1-A75-FQ2 $^{ m Note}$	7.5	117				
μPD44321361F1-A85-FQ2 Note	8.5	100				
μPD44321181F1-C75-FQ2 Note	7.5	117	2.5 ± 0.125	2.5 V LVTTL		
μPD44321181F1-C85-FQ2 Note	8.5	100				
μPD44321321F1-C75-FQ2 Note	7.5	117				
μPD44321321F1-C85-FQ2 Note	8.5	100				
μPD44321361F1-C75-FQ2 Note	7.5	117				
μ PD44321361F1-C85-FQ2 $^{ m Note}$	8.5	100				

Note Under development

(2/2)

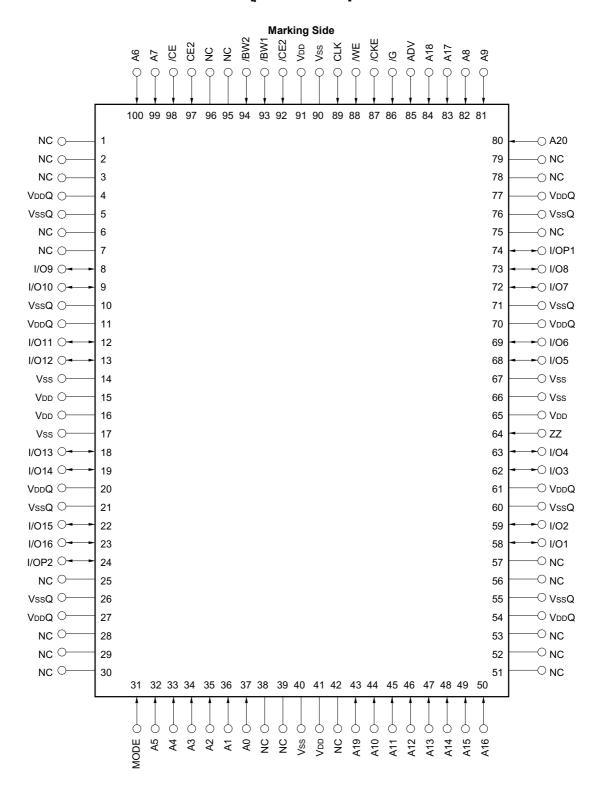
Part number	Access Time ns	Clock Frequency MHz	Core Supply Voltage V	I/O Interface	Operating Temperature °C	Package
μPD44321181GF-A65Y	6.5	133	3.3 ± 0.165	3.3 V or	-40 to +85	100-pin PLASTIC LQFP
μPD44321181GF-A75Y	7.5	117		2.5 V LVTTL		(14 x 20)
μPD44321181GF-A85Y	8.5	100				
μPD44321321GF-A65Y	6.5	133				
μPD44321321GF-A75Y	7.5	117				
μPD44321321GF-A85Y	8.5	100				
μPD44321361GF-A65Y	6.5	133				
μPD44321361GF-A75Y	7.5	117				
μPD44321361GF-A85Y	8.5	100				
μPD44321181GF-C75Y	7.5	117	2.5 ± 0.125	2.5 V LVTTL		
μPD44321181GF-C85Y	8.5	100				
μPD44321321GF-C75Y	7.5	117				
μPD44321321GF-C85Y	8.5	100				
μPD44321361GF-C75Y	7.5	117				
μPD44321361GF-C85Y	8.5	100				
μ PD44321181F1-A65Y-FQ2 Note	6.5	133	3.3 ± 0.165	3.3 V or		165-pin PLASTIC FBGA
μ PD44321181F1-A75Y-FQ2 Note	7.5	117		2.5 V LVTTL		(15 x 17)
μ PD44321181F1-A85Y-FQ2 Note	8.5	100				
μ PD44321321F1-A65Y-FQ2 Note	6.5	133				
μPD44321321F1-A75Y-FQ2 Note	7.5	117				
μ PD44321321F1-A85Y-FQ2 Note	8.5	100				
μ PD44321361F1-A65Y-FQ2 Note	6.5	133				
μ PD44321361F1-A75Y-FQ2 Note	7.5	117				
μ PD44321361F1-A85Y-FQ2 Note	8.5	100				
μPD44321181F1-C75Y-FQ2 Note	7.5	117	2.5 ± 0.125	2.5 V LVTTL		
μPD44321181F1-C85Y-FQ2 Note	8.5	100				
μPD44321321F1-C75Y-FQ2 Note	7.5	117				
μPD44321321F1-C85Y-FQ2 Note	8.5	100				
μPD44321361F1-C75Y-FQ2 Note	7.5	117				
μPD44321361F1-C85Y-FQ2 Note	8.5	100				

Note Under development

Pin Configurations

/xxx indicates active low signal.

100-pin PLASTIC LQFP (14 \times 20) [μ PD44321181GF]



Remark Refer to Package Drawing for the 1-pin index mark.

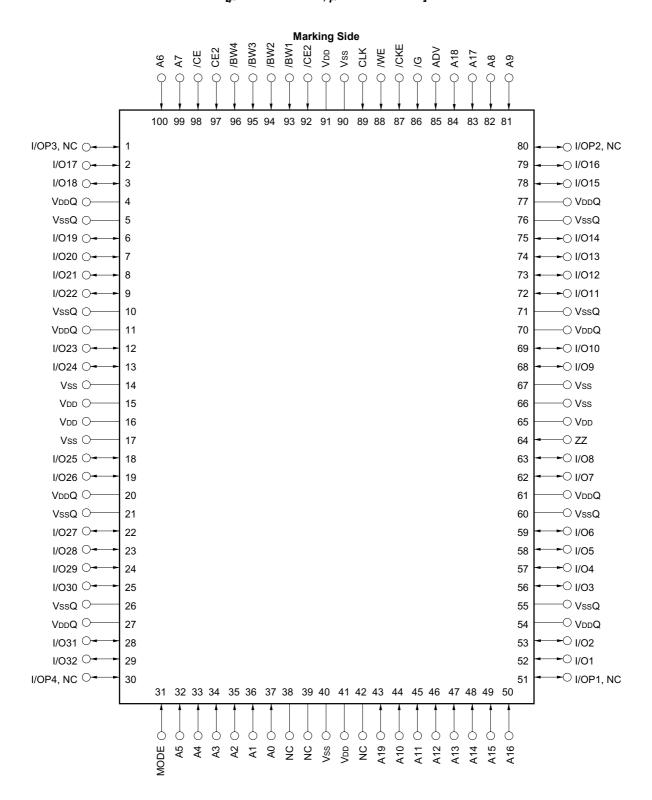


★ Pin Identifications

[μPD44321181GF]

Symbol	Pin No.	Description
A0 to A20	37, 36, 35, 34, 33, 32, 100, 99, 82, 81,	Synchronous Address Input
	44, 45, 46, 47, 48, 49, 50, 83, 84, 43, 80	
I/O1 to I/O16	58, 59, 62, 63, 68, 69, 72, 73, 8, 9, 12, 13,	Synchronous Data In,
	18, 19, 22, 23	Synchronous / Asynchronous Data Out
I/OP1	74	Synchronous Data In (Parity),
I/OP2	24	Synchronous / Asynchronous Data Out (Parity)
ADV	85	Synchronous Address Load / Advance Input
/CE, CE2, /CE2	98, 97, 92	Synchronous Chip Enable Input
WE	88	Synchronous Write Enable Input
/BW1, /BW2	93, 94	Synchronous Byte Write Enable Input
/G	86	Asynchronous Output Enable Input
CLK	89	Clock Input
/CKE	87	Synchronous Clock Enable Input
MODE	31	Asynchronous Burst Sequence Select Input
		Have to tied to VDD or Vss during normal operation
ZZ	64	Asynchronous Power Down State Input
V _{DD}	15, 16, 41, 65, 91	Power Supply
Vss	14, 17, 40, 66, 67, 90	Ground
V _{DD} Q	4, 11, 20, 27, 54, 61, 70, 77	Output Buffer Power Supply
VssQ	5, 10, 21, 26, 55, 60, 71, 76	Output Buffer Ground
NC	1, 2, 3, 6, 7, 25, 28, 29, 30, 38, 39, 42,	No Connection
	51, 52, 53, 56, 57, 75, 78, 79, 95, 96	

100-pin PLASTIC LQFP (14 × 20) [μPD44321321GF, μPD44321361GF]



Remark Refer to Package Drawing for the 1-pin index mark.



$[\mu PD44321321GF, \mu PD44321361GF]$

Symbol	Pin No.	Description
A0 to A19	37, 36, 35, 34, 33, 32, 100, 99, 82, 81, 44,	Synchronous Address Input
	45, 46, 47, 48, 49, 50, 83, 84, 43	
I/O1 to I/O32	52, 53, 56, 57, 58, 59, 62, 63, 68, 69, 72,	Synchronous Data In,
	73, 74, 75, 78, 79, 2, 3, 6, 7, 8, 9, 12, 13,	Synchronous / Asynchronous Data Out
	18, 19, 22, 23, 24, 25, 28, 29	
I/OP1, NC Note	51	Synchronous Data In (Parity),
I/OP2, NC Note	80	Synchronous / Asynchronous Data Out (Parity)
I/OP3, NC Note	1	
I/OP4, NC Note	30	
ADV	85	Synchronous Address Load / Advance Input
/CE, CE2, /CE2	98, 97, 92	Synchronous Chip Enable Input
WE	88	Synchronous Write Enable Input
/BW1 to /BW4	93, 94, 95, 96	Synchronous Byte Write Enable Input
/G	86	Asynchronous Output Enable Input
CLK	89	Clock Input
/CKE	87	Synchronous Clock Enable Input
MODE	31	Asynchronous Burst Sequence Select Input
		Have to tied to VDD or Vss during normal operation
ZZ	64	Asynchronous Power Down State Input
V _{DD}	15, 16, 41, 65, 91	Power Supply
Vss	14, 17, 40, 66, 67, 90	Ground
V _{DD} Q	4, 11, 20, 27, 54, 61, 70, 77	Output Buffer Power Supply
VssQ	5, 10, 21, 26, 55, 60, 71, 76	Output Buffer Ground
NC	38, 39, 42	No Connection

Note NC (No Connection) is used in the μ PD44321321GF. I/OP1 to I/OP4 are used in the μ PD44321361GF.

165-pin PLASTIC FBGA (15 x 17) [μPD44321181F1]

	Top View										
	1	2	3	4	5	6	7	8	9	10	11
Α	NC	A7	/CE	/BW2	NC	/CE2	/CKE	ADV	A17	A9	A20
В	NC	A6	CE2	NC	/BW1	CLK	WE	/G	A18	A8	NC
С	NC	NC	$V_{DD}Q$	Vss	Vss	Vss	Vss	Vss	$V_{DD}Q$	NC	I/OP1
D	NC	1/09	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	NC	I/O8
Е	NC	I/O10	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	NC	1/07
F	NC	I/O11	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	NC	I/O6
G	NC	I/O12	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	NC	I/O5
Н	NC	V_{DD}	NC	V_{DD}	Vss	Vss	Vss	V_{DD}	NC	NC	ZZ
J	I/O13	NC	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O4	NC
K	I/O14	NC	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O3	NC
L	I/O15	NC	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O2	NC
М	I/O16	NC	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O1	NC
N	I/OP2	NC	$V_{DD}Q$	Vss	NC	NC	NC	Vss	$V_{DD}Q$	NC	NC
Р	NC	NC	A4	A12	TDI	A1	TDO	A19	A13	A14	NC
R	MODE	A5	A3	A2	TMS	A0	TCK	A10	A11	A15	A16

Remark Refer to Package Drawings for the index mark.



★ [μPD44321181F1]

Symbol	Pin No.	Description
A0 to A20	6R, 6P, 4R, 3R, 3P, 2R, 2B, 2A, 10B, 10A, 8R, 9R,	Synchronous Address Input
	4P, 9P, 10P, 10R, 11R, 9A, 9B, 8P, 11A	
I/O1 to I/O16	10M, 10L, 10K, 10J, 11G, 11F, 11E, 11D, 2D, 2E,	Synchronous Data In,
	2F, 2G, 1J, 1K, 1L, 1M	Synchronous / Asynchronous Data Out
I/OP1	11C	Synchronous Data In (Parity),
I/OP2	1N	Synchronous / Asynchronous Data Out (Parity)
ADV	8A	Synchronous Address Load / Advance Input
/CE, CE2, /CE2	3A, 3B, 6A	Synchronous Chip Enable Input
/WE	7B	Synchronous Write Enable Input
/BW1, /BW2	5B, 4A	Synchronous Byte Write Enable Input
/G	8B	Asynchronous Output Enable Input
CLK	6B	Clock Input
/CKE	7A	Synchronous Clock Enable Input
MODE	1R	Asynchronous Burst Sequence Select Input
		Have to tied to VDD or Vss during normal operation
ZZ	11H	Asynchronous Power Down State Input
V _{DD}	2H, 4D, 4E, 4F, 4G, 4H, 4J, 4K, 4L, 4M, 8D, 8E,	Power Supply
	8F, 8G, 8H, 8J, 8K, 8L, 8M	
Vss	4C, 4N, 5C, 5D, 5E, 5F, 5G, 5H, 5J, 5K, 5L, 5M,	Ground
	6C, 6D, 6E, 6F, 6G, 6H, 6J, 6K, 6L, 6M, 7C, 7D,	
	7E, 7F, 7G, 7H, 7J, 7K, 7L, 7M, 8C, 8N	
V _{DD} Q	3C, 3D, 3E, 3F, 3G, 3J, 3K, 3L, 3M, 3N, 9C, 9D,	Output Buffer Power Supply
	9E, 9F, 9G, 9J, 9K, 9L, 9M, 9N	
NC	1A, 1B, 1C, 1D, 1E, 1F, 1G, 1H, 1P, 2C, 2J, 2K,	No Connection
	2L, 2M, 2N, 2P, 3H, 4B, 5A, 5N, 6N, 7N, 9H, 10C,	
	10D, 10E, 10F, 10G, 10H, 10N, 11B, 11J, 11K,	
	11L, 11M, 11N, 11P	
TMS	5R	Test Mode Select (JTAG)
TDI	5P	Test Data Input (JTAG)
TCK	7R	Test Clock Input (JTAG)
TDO	7P	Test Data Output (JTAG)

165-pin PLASTIC FBGA (15 x 17) [μΡD44321321F1, μΡD44321361F1]

	Top View										
	1	2	3	4	5	6	7	8	9	10	11
Α	NC	A7	/CE	/BW3	/BW2	/CE2	/CKE	ADV	A17	A9	NC
В	NC	A6	CE2	/BW4	/BW1	CLK	/WE	/G	A18	A8	NC
С	I/OP3,NC	NC	$V_{DD}Q$	Vss	Vss	Vss	Vss	Vss	$V_{DD}Q$	NC	I/OP2,NC
D	I/O17	I/O21	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O16	I/O12
Ε	I/O18	I/O22	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O15	I/O11
F	I/O19	I/O23	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O14	I/O10
G	I/O20	I/O24	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O13	1/09
Н	NC	V_{DD}	NC	V_{DD}	Vss	Vss	Vss	V_{DD}	NC	NC	ZZ
J	I/O25	I/O29	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O8	1/04
K	I/O26	I/O30	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	1/07	I/O3
L	I/O27	I/O31	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O6	I/O2
М	I/O28	I/O32	$V_{DD}Q$	V_{DD}	Vss	Vss	Vss	V_{DD}	$V_{DD}Q$	I/O5	I/O1
N	I/OP4,NC	NC	$V_{DD}Q$	Vss	NC	NC	NC	Vss	$V_{DD}Q$	NC	I/OP1,NC
Р	NC	NC	A4	A12	TDI	A1	TDO	A19	A13	A14	NC
R	MODE	A5	А3	A2	TMS	A0	TCK	A10	A11	A15	A16

Remark Refer to **Package Drawings** for the index mark.



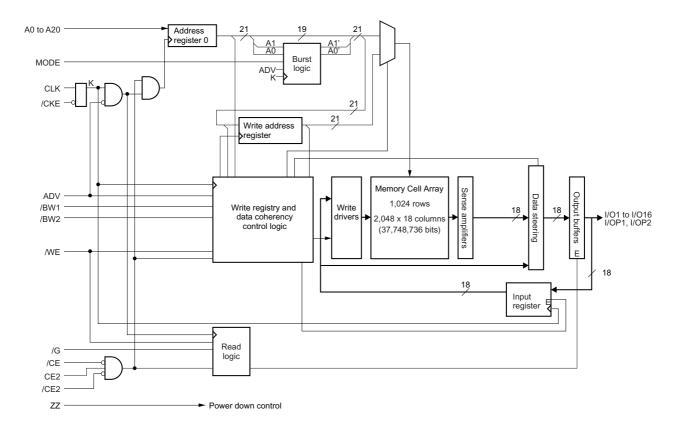
[μ PD44321321GF, μ PD44321361GF]

Symbol	Pin No.	Description
A0 to A19	6R, 6P, 4R, 3R, 3P, 2R, 2B, 2A, 10B, 10A, 8R, 9R,	Synchronous Address Input
	4P, 9P, 10P, 10R, 11R, 9A, 9B, 8P	
I/O1 to I/O32	11M, 11L, 11K, 11J, 10M, 10L, 10K, 10J, 11G, 11F,	Synchronous Data In,
	11E, 11D, 10G, 10F, 10E, 10D, 1D, 1E, 1F, 1G, 2D,	Synchronous / Asynchronous Data Out
	2E, 2F, 2G,1J, 1K, 1L, 1M, 2J, 2K, 2L, 2M	
I/OP1, NC Note	11N	Synchronous Data In (Parity),
I/OP2, NC Note	11C	Synchronous / Asynchronous Data Out (Parity)
I/OP3, NC Note	1C	
I/OP4, NC Note	1N	
ADV	8A	Synchronous Address Load / Advance Input
/CE, CE2, /CE2	3A, 3B, 6A	Synchronous Chip Enable Input
/WE	7B	Synchronous Write Enable Input
/BW1 to /BW4	5B, 5A, 4A, 4B	Synchronous Byte Write Enable Input
/G	8B	Asynchronous Output Enable Input
CLK	6B	Clock Input
/CKE	7A	Synchronous Clock Enable Input
MODE	1R	Asynchronous Burst Sequence Select Input
		Have to tied to VDD or Vss during normal operation
ZZ	11H	Asynchronous Power Down State Input
V _{DD}	2H, 4D, 4E, 4F, 4G, 4H, 4J, 4K, 4L, 4M, 8D, 8E, 8F,	Power Supply
	8G, 8H, 8J, 8K, 8L, 8M	
Vss	4C, 4N, 5C, 5D, 5E, 5F, 5G, 5H, 5J, 5K, 5L, 5M,	Ground
	6C, 6D, 6E, 6F, 6G, 6H, 6J, 6K, 6L, 6M, 7C, 7D,	
	7E, 7F, 7G, 7H, 7J, 7K, 7L, 7M, 8C, 8N	
V _{DD} Q	3C, 3D, 3E, 3F, 3G, 3J, 3K, 3L, 3M, 3N, 9C, 9D, 9E,	Output Buffer Power Supply
	9F, 9G, 9J, 9K, 9L, 9M, 9N	
NC	1A, 1B, 1H, 1P, 2C, 2N, 2P, 3H, 5N, 6N, 7N, 9H,	No Connection
	10C, 10H, 10N, 11A, 11B, 11P	
TMS	5R	Test Mode Select (JTAG)
TDI	5P	Test Data Input (JTAG)
TCK	7R	Test Clock Input (JTAG)
TDO	7P	Test Data Output (JTAG)

Note NC (No Connection) is used in the μ PD44321321GF. I/OP1 to I/OP4 are used in the μ PD44321361GF.

Block Diagrams

★ [µPD44321181]



Burst Sequence

★ [μPD44321181]

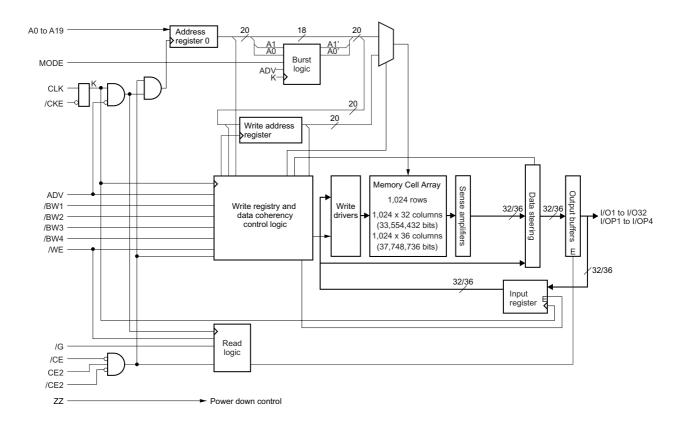
Interleaved Burst Sequence Table (MODE = VDD)

External Address	A20 to A2, A1, A0
1st Burst Address	A20 to A2, A1, /A0
2nd Burst Address	A20 to A2, /A1, A0
3rd Burst Address	A20 to A2, /A1, /A0

Linear Burst Sequence Table (MODE = Vss)

External Address	A20 to A2, 0, 0	A20 to A2, 0, 1	A20 to A2, 1, 0	A20 to A2, 1, 1
1st Burst Address	A20 to A2, 0, 1	A20 to A2, 1, 0	A20 to A2, 1, 1	A20 to A2, 0, 0
2nd Burst Address	A20 to A2, 1, 0	A20 to A2, 1, 1	A20 to A2, 0, 0	A20 to A2, 0, 1
3rd Burst Address	A20 to A2, 1, 1	A20 to A2, 0, 0	A20 to A2, 0, 1	A20 to A2, 1, 0

[μPD44321321, μPD44321361]



[μPD44321321, μPD44321361]

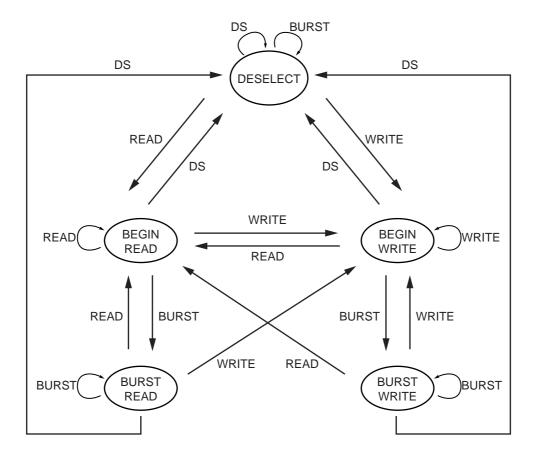
Interleaved Burst Sequence Table (MODE = VDD)

External Address	A19 to A2, A1, A0
1st Burst Address	A19 to A2, A1, /A0
2nd Burst Address	A19 to A2, /A1, A0
3rd Burst Address	A19 to A2, /A1, /A0

Linear Burst Sequence Table (MODE = Vss)

External Address	A19 to A2, 0, 0	A19 to A2, 0, 1	A19 to A2, 1, 0	A19 to A2, 1, 1
1st Burst Address	A19 to A2, 0, 1	A19 to A2, 1, 0	A19 to A2, 1, 1	A19 to A2, 0, 0
2nd Burst Address	A19 to A2, 1, 0	A19 to A2, 1, 1	A19 to A2, 0, 0	A19 to A2, 0, 1
3rd Burst Address	A19 to A2, 1, 1	A19 to A2, 0, 0	A19 to A2, 0, 1	A19 to A2, 1, 0

State Diagram



Command	Operation
DS	Deselect
Read	New Read
Write	New Write
Burst	Burst Read, Burst Write or Continue Deselect

Remarks 1. States change on the rising edge of the clock.

2. A Stall or Ignore Clock Edge cycle is not shown in the above diagram. This is because /CKE HIGH only blocks the clock (CLK) input and does not change the state of the device.

Asynchronous Truth Table

Operation	/G	I/O
Read Cycle	L	Data-Out
Read Cycle	Н	High-Z
Write Cycle	×	High-Z, Data-In
Deselected	×	High-Z

Remark ×: don't care

Synchronous Truth Table

Operation	/CE	CE2	/CE2	ADV	WE	/BWs	/CKE	CLK	I/O	Address	Note
Deselected	Н	×	×	L	×	×	L	$L\toH$	High-Z	None	1
Deselected	×	L	×	L	×	×	L	$L \rightarrow H$	High-Z	None	1
Deselected	×	×	Н	L	×	×	L	$L\toH$	High-Z	None	1
Continue Deselected	×	×	×	Н	×	×	L	$L \rightarrow H$	High-Z	None	1
Read Cycle / Begin Burst	L	Н	L	L	Н	×	L	$L\toH$	Data-Out	External	
Read Cycle / Continue Burst	×	×	×	Н	×	×	L	$L\toH$	Data-Out	Next	
Write Cycle / Begin Burst	L	Н	L	L	L	L	L	$L \rightarrow H$	Data-In	External	
Write Cycle / Continue Burst	×	×	×	Н	×	L	L	$L \rightarrow H$	Data-In	Next	
Write Cycle / Write Abort	L	Н	L	L	L	Н	L	$L \rightarrow H$	High-Z	External	
Write Cycle / Write Abort	×	×	×	Н	×	Н	L	$L \rightarrow H$	High-Z	Next	
Stall / Ignore Clock Edge	×	×	×	×	×	×	Н	$L\toH$	-	Current	2

Notes 1. Deselect status is held until new "Begin Burst" entry.

2. If an Ignore Clock Edge command occurs during a read operation, the I/O bus will remain active (Low impedance). If it occurs during a write cycle, the bus will remain High impedance. No write operation will be performed during the Ignore Clock Edge cycle.

Remarks 1. \times : don't care

2. /BWs = L means any one or more byte write enables (/BW1, /BW2, /BW3 or /BW4) are LOW. /BWs = H means all byte write enables (/BW1, /BW2, /BW3 or /BW4) are HIGH.

Partial Truth Table for Write Enables

★ [μPD44321181]

Operation	/WΕ	/BW1	/BW2
Read Cycle	Н	×	×
Write Cycle / Byte 1 (I/O [1:8], I/OP1)	L	L	Н
Write Cycle / Byte 2 (I/O [9:16], I/OP2)	L	Н	L
Write Cycle / All Bytes	L	L	L
Write Abort / NOP	L	Н	Н

Remark ×: don't care

[μPD44321321, μPD44321361]

Operation	WE	/BW1	/BW2	/BW3	/BW4
Read Cycle	Н	×	×	×	×
Write Cycle / Byte 1 (I/O [1:8], I/OP1)	L	L	Н	Н	Н
Write Cycle / Byte 2 (I/O [9:16], I/OP2)	L	Н	L	Н	Н
Write Cycle / Byte 3 (I/O [17:24], I/OP3)	L	Н	Н	L	Н
Write Cycle / Byte 4 (I/O [25:32], I/OP4)	L	Н	Н	Н	L
Write Cycle / All Bytes	L	L	L	L	L
Write Abort / NOP	L	Н	Н	Н	Н

Remark ×: don't care

ZZ (Sleep) Truth Table

ZZ	Chip Status
≤ 0.2 V	Active
Open	Active
≥ V _{DD} – 0.2 V	Sleep



Electrical Specifications

Absolute Maximum Ratings

	Parameter	Symbol	Cor	Conditions			MAX.	Unit
*	Supply voltage	V_{DD}		-A65, -A75, -A85	-0.5		+4.0	V
				-A65Y, -A75Y, -A85Y				
				-C75, -C85	-0.5		+3.0	
				-C75Y, -C85Y				
	Output supply voltage	$V_{DD}Q$			-0.5		V _{DD}	V
	Input voltage	VIN			-0.5 Note		V _{DD} + 0.5	V
	Input / Output voltage	VI/O			-0.5 Note		V _{DD} Q + 0.5	V
*	Operating ambient	TA	-A65, -A75, -A	85, -C75, -C85	0		70	°C
	temperature		-A65Y, -A75Y,	-A85Y, -C75Y, -C85Y	-4 0		+85	
	Storage temperature	T _{stg}			– 55		+125	°C

Note -2.0 V (MIN.) (Pulse width: 2 ns)

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Recommended DC Operating Conditions

(1/2)

*	Parameter	Symbol	Conditions	-A	.65, -A75, -A	65, -A75, -A85		
				-A65	SY, -A75Y, -A	\85Y		
				MIN.	TYP.	MAX.		
	Supply voltage	V _{DD}		3.135	3.3	3.465	V	
	2.5 V LVTTL Interface							
	Output supply voltage	$V_{DD}Q$		2.375	2.5	2.9	V	
	High level input voltage	VIH		1.7		V _{DD} Q + 0.3	V	
	Low level input voltage	VıL		-0.3 Note		+0.7	٧	
	3.3 V LVTTL Interface							
	Output supply voltage	$V_{DD}Q$		3.135	3.3	3.465	V	
	High level input voltage	VIH		2.0		V _{DD} Q +	V	
	Low level input voltage	VIL		-0.3 Note		+0.8	V	

Note -0.8 V (MIN.) (Pulse width: 2 ns)

Recommended DC Operating Conditions

(2/2)

*	Parameter	Symbol	Conditions	-	-C75, -C85 -C75Y, -C85Y		
				MIN.	TYP.	MAX.	
	Supply voltage	V_{DD}		2.375	2.5	2.625	V
	Output supply voltage	$V_{DD}Q$		2.375	2.5	2.625	٧
	High level input voltage	VIH		1.7		V _{DD} Q + 0.3	V
	Low level input voltage	VIL		-0.3 Note		+0.7	V

Note -0.8 V (MIN.) (Pulse width: 2 ns)

DC Characteristics (V_{DD} = 3.3 ± 0.165 V or 2.5 ± 0.125 V)

Parameter	Symbol	Test condition		MIN.	TYP.	MAX.	Unit
Input leakage current	lu	Vin (except ZZ, MODE) = 0 V f	to V _{DD}	-2		+2	μΑ
I/O leakage current	ILO	V _{VO} = 0 V to V _{DD} Q, Outputs are	e disabled.	-2		+2	μΑ
Operating supply current	IDD	Device selected,	-A65			310	mA
		Cycle = MAX.	-A65Y				
		$V_{IN} \le V_{IL} \text{ or } V_{IN} \ge V_{IH},$	-A75, -C75			290	
		I _{I/O} = 0 mA	-A75Y, -C75Y				
			-A85, -C85			270	
			-A85Y, -C85Y				
Standby supply current	IsB	Device deselected, Cycle = 0	MHz,			70	mA
		$V_{IN} \le V_{IL}$ or $V_{IN} \ge V_{IH}$, All inputs	are static.				
	I _{SB1}	Device deselected, Cycle = 0	Device deselected, Cycle = 0 MHz, $V_{\text{IN}} \leq 0.2 \text{ V or } V_{\text{IN}} \geq V_{\text{DD}} - 0.2 \text{ V},$			60	
		$V_{IN} \le 0.2 \text{ V or } V_{IN} \ge V_{DD} - 0.2 \text{ V}$					
		V _{I/O} ≤ 0.2 V, All inputs are stat	ic.				
	I _{SB2}	Device deselected, Cycle = M	AX.			110	
		$V_{IN} \le V_{IL} \text{ or } V_{IN} \ge V_{IH}$					
Power down supply current	Isbzz	$ZZ \ge V_{DD} - 0.2 \text{ V}, \text{ V/O} \le V_{DD}Q$	+ 0.2 V			60	mA
2.5 V LVTTL Interface							
High level output voltage	Vон	Iон = −2.0 mA		1.7			V
		Iон = −1.0 mA		2.1			
Low level output voltage	Vol	I _{OL} = +2.0 mA				0.7	V
		I _{OL} = +1.0 mA				0.4	
3.3 V LVTTL Interface							
High level output voltage	Vон	Iон = −4.0 mA		2.4			V
Low level output voltage	Vol	I _{OL} = +8.0 mA				0.4	V

Capacitance (T_A = 25 °C, f = 1MHz)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Cin	V _{IN} = 0 V			6.0	pF
Input / Output capacitance	C _{I/O}	V _{VO} = 0 V			8.0	pF
Clock input capacitance	Cclk	V _{clk} = 0 V			6.0	pF

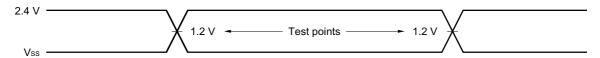
Remark These parameters are periodically sampled and not 100% tested.

AC Characteristics ($V_{DD} = 3.3 \pm 0.165 \text{ V or } 2.5 \pm 0.125 \text{ V}$)

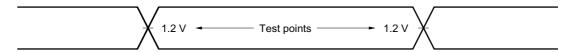
AC Test Conditions

2.5 V LVTTL Interface

Input waveform (Rise / Fall time ≤ 2.4 ns)

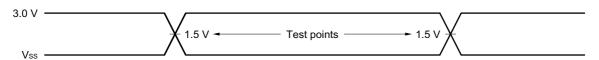


Output waveform

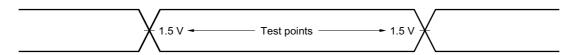


3.3 V LVTTL Interface

Input waveform (Rise / Fall time ≤ 3.0 ns)



Output waveform

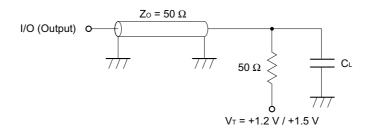


Output load condition

C_L: 30 pF

5 pF (TKHQX1, TKHQX2, TGLQX, TGHQZ, TKHQZ)

Figure External load at test



 $\textbf{Remark} \ \ \textbf{CL} \ \text{includes capacitances of the probe and jig, and stray capacitances}.$

Read and Write Cycle

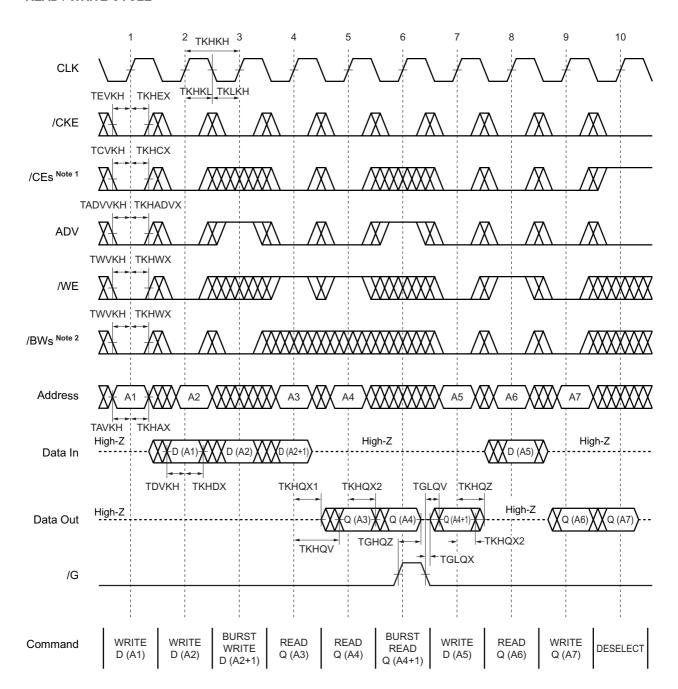
\star	

Parameter		Symbol			65 65Y		-C75 -C75Y	1	-C85 -C85Y	Unit	Notes
				(133 MHz)		(117 MHz)		(100 MHz)			
		Standard	Alias	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Cycle time		TKHKH	TCYC	7.5	_	8.6	_	10	_	ns	
Clock access	time	TKHQV	TCD	_	6.5	_	7.5	_	8.5	ns	
Output enable	access time	TGLQV	TOE	_	3.5	_	3.5	_	3.5	ns	
Clock high to	output active	TKHQX1	TDC1	2.5	_	2.5	_	2.5	_	ns	1, 2
Clock high to	output change	TKHQX2	TDC2	2.5	-	2.5	-	2.5	-	ns	
Output enable	to output active	TGLQX	TOLZ	0	_	0	_	0	_	ns	1
Output disable	e to output High-Z	TGHQZ	TOHZ	0	3.5	0	3.5	0	3.5	ns	1
Clock high to	output High-Z	TKHQZ	TCZ	2.5	5	2.5	5	2.5	5	ns	1, 2
Clock high pulse width		TKHKL	TCH	2.5	-	2.5	-	2.5	-	ns	
Clock low puls	Clock low pulse width		TCL	2.5	_	2.5	_	2.5	_	ns	
Setup times	Address	TAVKH	TAS	1.5	_	1.5	_	2	_	ns	
	Address advance	TADVVKH	TADVS								
	Clock enable	TEVKH	TCES								
	Chip enable	TCVKH	TCSS								
	Data in	TDVKH	TDS								
	Write enable	TWVKH	TWS								
Hold times	Address	TKHAX	TAH	0.5	_	0.5	_	0.5	_	ns	
	Address advance	TKHADVX	TADVH								
	Clock enable	TKHEX	TCEH								
	Chip enable	TKHCX	TCSH								
	Data in	TKHDX	TDH								
	Write enable	TKHWX	TWH								
Power down e	entry time	TZZE	TZZE	_	7.5	_	8.6	_	10	ns	
Power down r	ecovery time	TZZR	TZZR	_	7.5	_	8.6	_	10	ns	

Notes 1. Transition is measured ± 200 mV from steady state.

2. To avoid bus contention, the output buffers are designed such that TKHQZ (device turn-off) is faster than TKHQX1 (device turn-on) at a given temperature and voltage. The specs as shown do not imply bus contention because TKHQX1 is a min. parameter that is worse case at totally different conditions (TA min., VDD max.) than TKHQZ, which is a max. parameter (worse case at TA max., VDD min.).

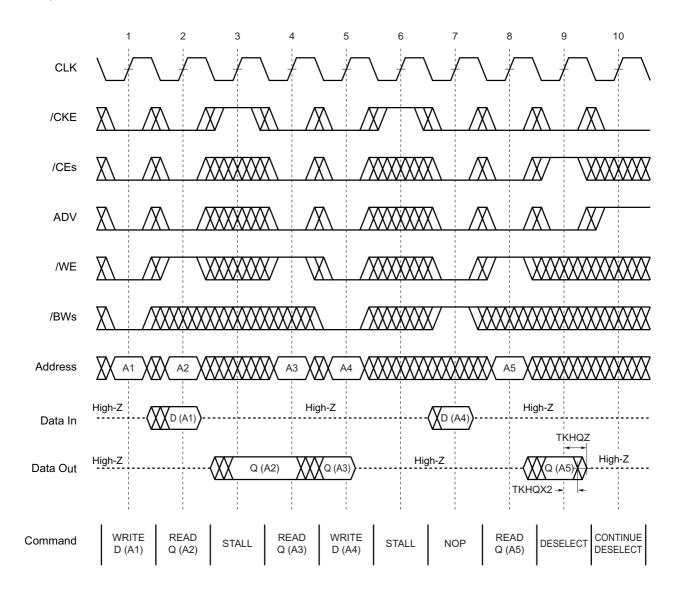
READ / WRITE CYCLE



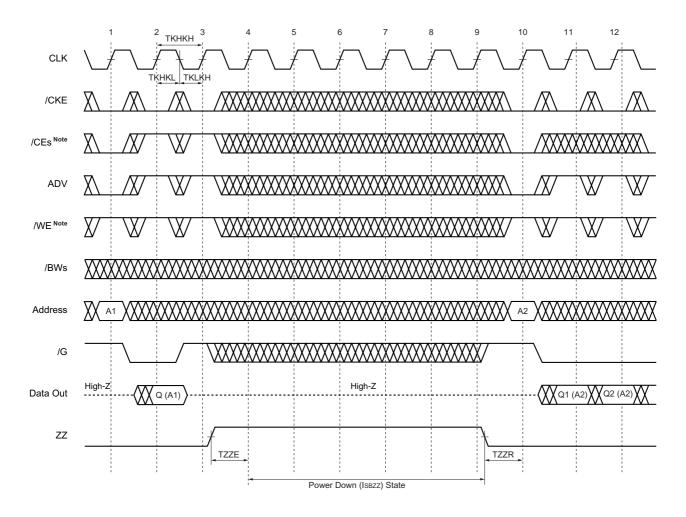
Notes 1. /CEs refers to /CE, CE2 and /CE2. When /CEs is LOW, /CE and /CE2 are LOW and CE2 is HIGH. When /CEs is HIGH, /CE and /CE2 are HIGH and CE2 is LOW.

2. /BWs refers to /BW1, /BW2, /BW3 and /BW4. When /BWs is LOW, any one or more byte write enables (/BW1, /BW2, /BW3 or /BW4) are LOW.

NOP, STALL AND DESELECT CYCLE



POWER DOWN (ZZ) CYCLE



Note /WE or /CEs must be held HIGH at CLK rising edge (clock edge No.3 in this figure) prior to power down state entry.

JTAG Specifications

★ Only the 165-pin PLASTIC FBGA package of μ PD44321181, μ PD44321321 and μ PD44321361 support a limited set of JTAG functions as in IEEE standard 1149.1.

Test Access Port (TAP) Pins

Pin Name	Description
TCK	Test Clock Input. All input are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.
TMS	Test Mode Select. This is the command input for the TAP controller state machine.
TDI	Test Data Input. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is deter-mined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction.
TDO	Test Data Output. Output changes in response to the falling edge of TCK. This is the output side of the serial registers placed between TDI and TDO.

Remark The device does not have TRST (TAP reset). The Test-Logic Reset state is entered while TMS is held high for five rising edges of TCK. The TAP controller state is also reset on the SRAM POWER-UP.

JTAG DC Characteristics (VDD = 3.3 ± 0.165 V)

(1/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Note
JTAG Input leakage current	lu	$0 \text{ V} \leq V_{IN} \leq V_{DD}$	-5.0	ı	+5.0	μΑ	
JTAG I/O leakage current	ILO	$0 \text{ V} \leq V_{IN} \leq V_{DD}Q$,	-5.0	1	+5.0	μΑ	
		Outputs disabled					
JTAG input high voltage	VIH		2.0	1	V _{DD} +0.3	V	
JTAG input low voltage	VIL		-0.3	_	+0.5	٧	
JTAG output high voltage	Vон	Iон = -4 mA	2.4	_	_	V	
JTAG output low voltage	Vol	IoL = 8 mA	_	_	0.4	٧	

JTAG DC Characteristics ($V_{DD} = 2.5 \pm 0.125 \text{ V}$)

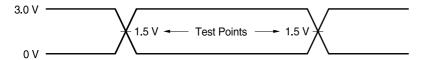
(2/2)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Note
JTAG Input leakage current	lu	$0 \text{ V} \leq V_{IN} \leq V_{DD}$	-5.0	-	+5.0	μΑ	
JTAG I/O leakage current	ILO	$0 \text{ V} \leq V_{IN} \leq V_{DD}Q$,	-5.0	_	+5.0	μΑ	
		Outputs disabled					
JTAG input high voltage	ViH		1.7	ı	V _{DD} +0.3	V	
JTAG input low voltage	VIL		-0.3	ı	+0.5	V	
JTAG output high voltage	Vон	Iон = -2.0 mA	1.7			٧	
		Iон = -1.0 mA	2.1				
JTAG output low voltage	Vol	I _{OL} = +2.0 mA			0.7	V	
		I _{OL} = +1.0 mA			0.4		

JTAG AC Test Conditions

★ [-A65, -A75, -A85, -A65Y, -A75Y, -A85Y]

Input waveform (rise / fall time ≤ 1 ns)

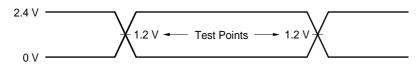


Output waveform



★ [-C75, -C85, -C75Y, -C85Y]

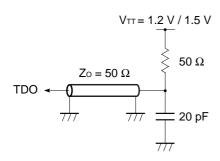
Input waveform (rise / fall time ≤ 1 ns)



Output waveform



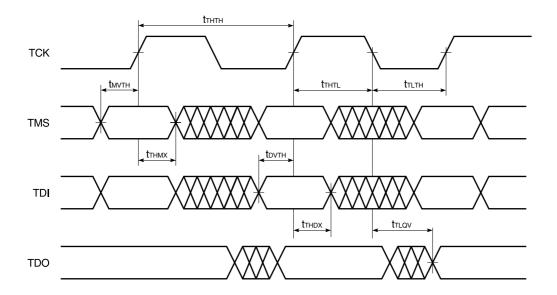
Output load



JTAG AC Characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Note
Clock Cycle Time (TCK)	tтнтн		100		1	ns	
Clock Phase Time (TCK)	t тнт∟ / t т∟тн		40		-	ns	
Setup Time (TMS / TDI)	tмvтн / tovтн		10		_	ns	
Hold Time (TMS / TDI)	tthmx / tthdx		10		_	ns	
TCK Low to TDO Valid (TDO)	t tlav		_		20	ns	

JTAG Timing Diagram





Scan Register Definition (1)

Register name	Description
Instruction register	The instruction register holds the instructions that are executed by the TAP controller when it is moved into the run-test/idle or the various data register state. The register can be loaded when it is placed between the TDI and TDO pins. The instruction register is automatically preloaded with the IDCODE instruction at power-up whenever the controller is placed in test-logic-reset state.
Bypass register	The bypass register is a single bit register that can be placed between TDI and TDO. It allows serial test data to be passed through the RAMs TAP to another device in the scan chain with as little delay as possible.
ID register	The ID Register is a 32 bit register that is loaded with a device and vendor specific 32 bit code when the controller is put in capture-DR state with the IDCODE command loaded in the instruction register. The register is then placed between the TDI and TDO pins when the controller is moved into shift-DR state.
Boundary register	The boundary register, under the control of the TAP controller, is loaded with the contents of the RAMs I/O ring when the controller is in capture-DR state and then is placed between the TDI and TDO pins when the controller is moved to shift-DR state. Several TAP instructions can be used to activate the boundary register. The Scan Exit Order tables describe which device bump connects to each boundary register location. The first column defines the bit's position in the boundary register. The shift register bit nearest TDO (i.e., first to be shifted out) is defined as bit 1. The second column is the name of the input or I/O at the bump and the third column is the bump number.

Scan Register Definition (2)

Register name	Bit size	Unit
Instruction register	3	bit
Bypass register	1	bit
ID register	32	bit
Boundary register	77	bit

★ ID Register Definition

Part number	Organization	ID [31:28] vendor revision no.	ID [27:12] part no.	ID [11:1] vendor ID no.	ID [0] fix bit
μPD44321181	2M x 18	XXXX	0000 0000 0010 1000	0000010000	1
μPD44321321	1M x 32	XXXX	0000 0000 0010 1001	00000010000	1
μPD44321361	1M x 36	XXXX	0000 0000 0010 1010	0000010000	1

★ SCAN Exit Order

[μ PD44321181 (2M words by 18 bits)]

Bump Bit Signal Bump Signal ID ID no. name no. name /CE2 NC 6N 40 6A 1 2 8P 41 /BW1 5B A19 3 A10 8R 42 NC 5A A11 9R /BW2 4A 5 9P 44 NC 4B A13 6 A14 10P 45 CE2 3B A15 10R 46 /CE 3A 8 11R 47 Α7 2A A16 9 NC 11P 48 Α6 2B 10 ZZ 11H 49 NC 1B 11N 50 NC 1A 11 NC 12 NC NC 1C 11M 51 13 NC 11L 52 NC 1D 1E 14 NC 11K 53 NC 1F 15 NC 11J 54 NC 16 1/01 10M 55 NC 1G 17 1/02 10L 56 1/09 2D 18 I/O3 10K 57 I/O10 2E 1/04 10J 58 I/O11 2F 19 59 I/O12 2G 20 1/05 11G I/O13 21 1/06 11F 60 1J 22 1/07 11E I/O14 61 1K 23 11D I/O15 1L 1/08 62 24 I/OP1 11C 63 I/O16 1M 25 NC 10F I/OP2 64 1N NC 26 NC 10E 65 2K 27 NC 10D NC 2L 28 NC 10G 67 NC 2M 2J 29 A20 11A 68 NC 30 NC 11B A5 2R MODE 31 Α9 10A 70 1R 71 3P 32 Α8 10B A4 33 A17 9A 72 А3 3R 34 A18 9B A2 4R 73 4P 35 ADV 8A 74 A12 36 /G 8B 75 Α1 6P 37 /CKE 7A 76 A0 6R 38 ΜE 7B

[μ PD44321321 (1M words by 32 bits)] [μ PD44321361 (1M words by 36 bits)]

Bit Signal Bump no. name ID no. name ID no. name ID no. name ID name	D:+	Cianal	Dum	D:+	Cianal	D
2 A19 8P 3 A10 8R 4 A11 9R 5 A13 9P 6 A14 10P 7 A15 10R 8 A16 11R 9 NC 11P 48 A6 2B 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O33 10G 25 I/O14 10F 66 I/O25 1J 59 I/O24 2G <td>Bit no.</td> <td>Signal name</td> <td>Bump ID</td> <td>Bit no.</td> <td>Signal name</td> <td>Bump ID</td>	Bit no.	Signal name	Bump ID	Bit no.	Signal name	Bump ID
3 A10 8R 4 A11 9R 5 A13 9P 6 A14 10P 7 A15 10R 8 A16 11R 9 NC 11P 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F	1	NC	6N	40	/CE2	6A
4 A11 9R 5 A13 9P 6 A14 10P 7 A15 10R 8 A16 11R 9 NC 11P 48 A6 2B 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F 26 I/O15 10E 25 I/O14 10F 26 I/O15 10E 27 I/O16 10D <td>2</td> <td>A19</td> <td>8P</td> <td>41</td> <td>/BW1</td> <td>5B</td>	2	A19	8P	41	/BW1	5B
5 A13 9P 6 A14 10P 7 A15 10R 8 A16 11R 9 NC 11P 48 A6 11P 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F 26 I/O15 10E 25 I/O14 10F 26 I/O15 10E <td>3</td> <td>A10</td> <td>8R</td> <td>42</td> <td>/BW2</td> <td>5A</td>	3	A10	8R	42	/BW2	5A
6 A14 10P 45 CE2 3B 7 A15 10R 46 /CE1 3A 8 A16 11R 47 A7 2A 9 NC 11P 48 A6 2B 10 ZZ 11H 49 NC 1B 11 I/OP1, NC 11N 50 NC 1A 12 I/O1 11L 51 I/OP3, NC 1C 13 I/O2 11L 52 I/O17 1D 16 I/O5 10M 55 I/O20 1G	4	A11	9R	43	/BW3	4A
7 A15 10R 8 A16 11R 9 NC 11P 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F 26 I/O15 10E 25 I/O14 10F 26 I/O15 10E 27 I/O16 10D 28 I/OP2, NC 11C 29 NC 11A </td <td>5</td> <td>A13</td> <td>9P</td> <td>44</td> <td>/BW4</td> <td>4B</td>	5	A13	9P	44	/BW4	4B
8 A16 11R 47 A7 2A 9 NC 11P 48 A6 2B 10 ZZ 11H 49 NC 1B 11 I/OP1, NC 11N 50 NC 1A 12 I/O1 11M 51 I/OP3, NC 1C 13 I/O2 11L 52 I/O17 1D 14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O8 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J<	6	A14	10P	45	CE2	3B
9 NC 11P 10 ZZ 11H 11 I/OP1, NC 11N 12 I/O1 11M 13 I/O2 11L 14 I/O3 11K 15 I/O4 11J 16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F 26 I/O15 10E 27 I/O16 10D 28 I/OP2, NC 11C 29 NC 11A 30 NC 11B 31 A9 10A 32 A8 10B 33 A17 9A 34 A18 9B 35 ADV 8A 36 /G 8B 37 /CKE 7A 38 NWE 7B	7	A15	10R	46	/CE1	3A
10 ZZ 11H 49 NC 1B 11 I/OP1, NC 11N 50 NC 1A 12 I/O1 11M 51 I/OP3, NC 1C 13 I/O2 11L 52 I/O17 1D 14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L	8	A16	11R	47	A7	2A
11 I/OP1, NC 11N 50 NC 1A 12 I/O1 11M 51 I/OP3, NC 1C 13 I/O2 11L 52 I/O17 1D 14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O15 10E 65 I/O30 2K	9	NC	11P	48	A6	2B
12 I/O1 11M 51 I/OP3, NC 1C 13 I/O2 11L 52 I/O17 1D 14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 65 I/O30 2K <	10	ZZ	11H	49	NC	1B
13 I/O2 11L 52 I/O17 1D 14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L	11	I/OP1, NC	11N	50	NC	1A
14 I/O3 11K 53 I/O18 1E 15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L <tr< td=""><td>12</td><td>I/O1</td><td>11M</td><td>51</td><td>I/OP3, NC</td><td>1C</td></tr<>	12	I/O1	11M	51	I/OP3, NC	1C
15 I/O4 11J 54 I/O19 1F 16 I/O5 10M 55 I/O20 1G 17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M	13	I/O2	11L	52	I/O17	1D
16 I/O5 10M 17 I/O6 10L 18 I/O7 10K 19 I/O8 10J 20 I/O9 11G 21 I/O10 11F 22 I/O11 11E 23 I/O12 11D 24 I/O13 10G 25 I/O14 10F 26 I/O15 10E 27 I/O16 10D 28 I/OP2, NC 11C 29 NC 11A 30 NC 11B 31 A9 10A 32 A8 10B 33 A17 9A 34 A18 9B 35 ADV 8A 36 /G 8B 37 /CKE 7A 38 /WE 7B	14	I/O3	11K	53	I/O18	1E
17 I/O6 10L 56 I/O21 2D 18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B	15	I/O4	11J	54	I/O19	1F
18 I/O7 10K 57 I/O22 2E 19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R	16	I/O5	10M	55	I/O20	1G
19 I/O8 10J 58 I/O23 2F 20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 75 A1 6P <tr< td=""><td>17</td><td>I/O6</td><td>10L</td><td>56</td><td>I/O21</td><td>2D</td></tr<>	17	I/O6	10L	56	I/O21	2D
20 I/O9 11G 59 I/O24 2G 21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R <	18	1/07	10K	57	I/O22	2E
21 I/O10 11F 60 I/O25 1J 22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G <	19	I/O8	10J	58	I/O23	2F
22 I/O11 11E 61 I/O26 1K 23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36	20	I/O9	11G	59	I/O24	2G
23 I/O12 11D 62 I/O27 1L 24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37	21	I/O10	11F	60	I/O25	1J
24 I/O13 10G 63 I/O28 1M 25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R	22	I/O11	11E	61	I/O26	1K
25 I/O14 10F 64 I/O29 2J 26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A A0 6R	23	I/O12	11D	62	I/O27	1L
26 I/O15 10E 65 I/O30 2K 27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R	24	I/O13	10G	63	I/O28	1M
27 I/O16 10D 66 I/O31 2L 28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R	25	I/O14	10F	64	I/O29	2J
28 I/OP2, NC 11C 67 I/O32 2M 29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B 7B 7B 7B	26	I/O15	10E	65	I/O30	2K
29 NC 11A 68 I/OP4, NC 1N 30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B	27	I/O16	10D	66	I/O31	2L
30 NC 11B 69 A5 2R 31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B	28	I/OP2, NC	11C	67	I/O32	2M
31 A9 10A 70 MODE 1R 32 A8 10B 71 A4 3P 33 A17 9A 72 A3 3R 34 A18 9B 73 A2 4R 35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B	29	NC	11A	68	I/OP4, NC	1N
32 A8 10B 33 A17 9A 34 A18 9B 35 ADV 8A 36 /G 8B 37 /CKE 7A 38 /WE 7B 71 A4 3P 72 A3 3R 73 A2 4R 74 A12 4P 75 A1 6P 76 A0 6R	30	NC	11B	69	A5	2R
33 A17 9A 34 A18 9B 35 ADV 8A 36 /G 8B 37 /CKE 7A 38 /WE 7B 72 A3 3R 73 A2 4R 74 A12 4P 75 A1 6P 76 A0 6R	31	A9	10A	70	MODE	1R
34 A18 9B 35 ADV 8A 36 /G 8B 37 /CKE 7A 38 /WE 7B 73 A2 4R 74 A12 4P 75 A1 6P 76 A0 6R	32	A8	10B	71	A4	3P
35 ADV 8A 74 A12 4P 36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B	33	A17	9A	72	A3	3R
36 /G 8B 75 A1 6P 37 /CKE 7A 76 A0 6R 38 /WE 7B	34	A18	9B	73	A2	4R
37 /CKE 7A 76 A0 6R 38 /WE 7B	35	ADV	8A	74	A12	4P
38 /WE 7B	36	/G	8B	75	A1	6P
	37	/CKE	7A	76	A0	6R
39 CLK 6B	38	/WE	7B			
	39	CLK	6B			

CLK

6B



JTAG Instructions

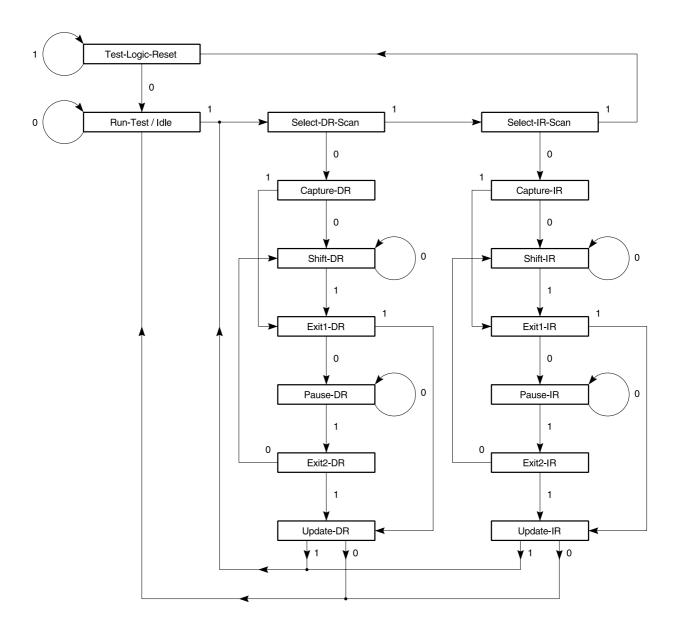
Instructions	Description
EXTEST	EXTEST is an IEEE 1149.1 mandatory public instruction. It is to be executed whenever the instruction register, whatever length it may be in the device, is loaded with all logic 0s. EXTEST is not implemented in this device. Therefore this device is not 1149.1 compliant. Nevertheless, this RAMs TAP does respond to an all zeros instruction, as follows. With the EXTEST (000) instruction loaded in the instruction register the RAM responds just as it does in response to the SAMPLE instruction, except the RAM output are forced to high impedance any time the instruction is loaded.
IDCODE	The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in capture-DR mode and places the ID register between the TDI and TDO pins in shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the test-logic-reset state.
BYPASS	The BYPASS instruction is loaded in the instruction register when the bypass register is placed between TDI and TDO. This occurs when the TAP controller is moved to the shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.
SAMPLE	Sample is a Standard 1149.1 mandatory public instruction. When the sample instruction is loaded in the instruction register, moving the TAP controller into the capture-DR state loads the data in the RAMs input and I/O buffers into the boundary scan register. Because the RAM clock(s) are independent from the TAP clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e., in a metastable state). Although allowing the TAP to sample metastable input will not harm the device, repeatable results cannot be expected. RAM input signals must be stabilized for long enough to meet the TAPs input data capture setup plus hold time (tcs plus tch). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the boundary scan register. Moving the controller to shift-DR state then places the boundary scan register between the TDI and TDO pins. This functionality is not Standard 1149.1 compliant.
SAMPLE-Z	If the SAMPLE-Z instruction is loaded in the instruction register, all RAM outputs are forced to an inactive drive state (High impedance) and the boundary register is connected between TDI and TDO when the TAP controller is moved to the shift-DR state.

JTAG Instruction Cording

IR2	IR1	IR0	Instruction	Note
0	0	0	EXTEST	1
0	0	1	IDCODE	
0	1	0	SAMPLE-Z	1
0	1	1	BYPASS	
1	0	0	SAMPLE	
1	0	1	BYPASS	
1	1	0	BYPASS	
1	1	1	BYPASS	

Note 1. TRISTATE all data drivers and CAPTURE the pad values into a SERIAL SCAN LATCH.

TAP Controller State Diagram



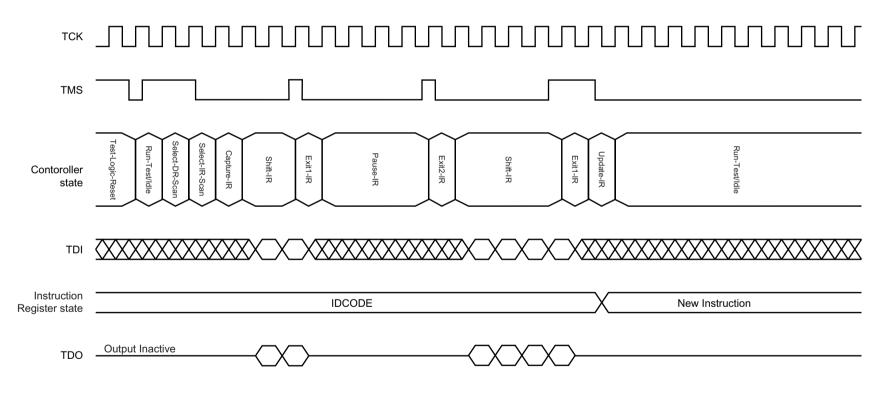
Disabling The Test Access Port

It is possible to use this device without utilizing the TAP. To disable the TAP Controller without interfering with normal operation of the device, TCK must be tied to Vss to preclude mid level inputs.

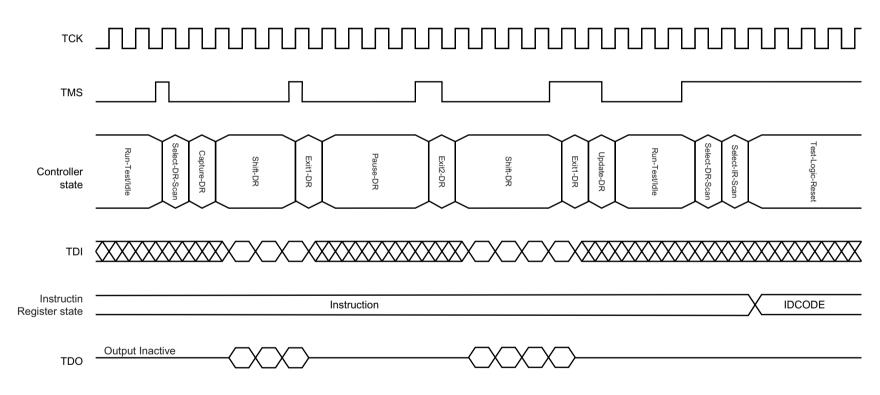
TDI and TMS are designed so an undriven input will produce a response identical to the application of a logic 1, and may be left unconnected. But they may also be tied to VDD through a 1 $k\Omega$ resistor.

TDO should be left unconnected.

Test Logic Operation (Instruction Scan)

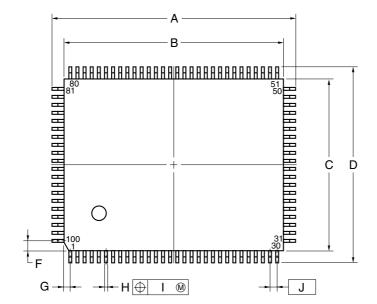


Test Logic (Data Scan)

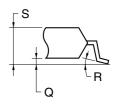


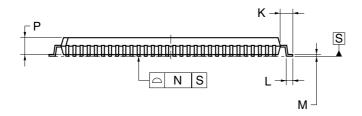
Package Drawings

100-PIN PLASTIC LQFP (14x20)



detail of lead end



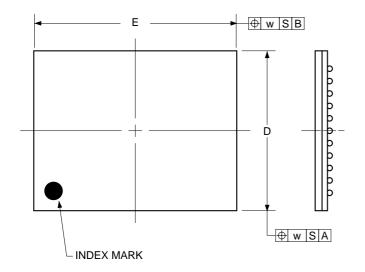


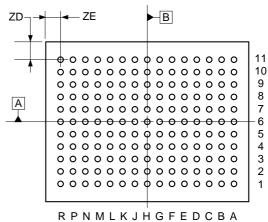
NOTE

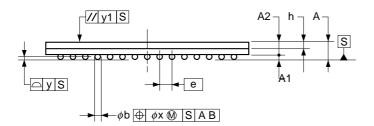
Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
Α	22.0±0.2
В	20.0±0.2
С	14.0±0.2
D	16.0±0.2
F	0.825
G	0.575
Н	$0.32^{+0.08}_{-0.07}$
I	0.13
J	0.65 (T.P.)
K	1.0±0.2
L	0.5±0.2
М	$0.17^{+0.06}_{-0.05}$
N	0.10
P	1.4
Q	0.125±0.075
R	3°+7° -3°
S	1.7 MAX.
	S100GF-65-8FT-1

165-PIN PLASTIC FBGA (15x17)







ITEM	MILLIMETERS			
D	15.00			
E	17.00			
ZD	2.50			
ZE	1.50			
е	1.00			
h	0.60			
Α	1.40			
A1	0.40			
A2	1.00			
b	0.45			
у	0.08			
х	0.08			
W	0.15			
v1	0.20			

This package drawing is a preliminary version. It may be changed in the future.

Recommended Soldering Condition

★ Please consult with our sales offices for soldering conditions of the μ PD44321181, μ PD44321321 and μ PD44321361.

★ Types of Surface Mount Devices

μPD44321181GF : 100-pin PLASTIC LQFP (14 x 20) μPD44321321GF : 100-pin PLASTIC LQFP (14 x 20) μPD44321361GF : 100-pin PLASTIC LQFP (14 x 20) μPD44321181F1-FQ2 : 165-pin PLASTIC FBGA (15 x 17) μPD44321321F1-FQ2 : 165-pin PLASTIC FBGA (15 x 17) μPD44321361F1-FQ2 : 165-pin PLASTIC FBGA (15 x 17)

Revision History

Edition/	Page		Type of	Location	Description
Date	This	Previous	revision		(Previous edition $ ightarrow$ This edition)
	edition	edition			
1st edition/	Throughout	Throughout	Modification	-	Preliminary Product Information
Dec. 2002					→ Preliminary Data Sheet
			Deletion	_	μPD44321161
			Addition	_	Extended operating temperature products
					(T _A = -40 to +85 °C)
	pp.2, 3	pp.2, 3	Addition	Ordering Information	Under development
					(165-pin PLASTIC FBGA (15 x 17))
	p.27	p.27	Addition	ID Register Definition	Addition of ID [27:12] part no.



[MEMO]

[MEMO]

NOTES FOR CMOS DEVICES -

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

2 HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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